

REF61xx 集成 ADC 驱动器缓冲器的高精度电压基准

1 特性

- 出色的温度漂移性能
 - 40°C 至 +125°C 时为 8ppm/°C (最大值)
- 极低噪声
 - 总噪声: 5 μV_{RMS} (使用 47 μF 电容时)
 - 1/f 噪声 (0.1Hz 至 10Hz): 3 $\mu\text{V}_{\text{PP/V}}$
- 集成 ADC 驱动器缓冲器
 - 低输出阻抗: < 50m Ω (0kHz-200kHz)
 - 首次使用 ADS8881 实现 18 位精确采样
 - 支持突发模式 DAQ 系统
- 低电源电流: 820 μA
- 低关断电流: 1 μA
- 高初始精度: $\pm 0.05\%$
- 超低噪声和失真
 - 信噪比 (SNR): 100.5dB, 总谐波失真 (THD): -125dB (ADS8881)
 - 信噪比 (SNR): 106dB, 总谐波失真 (THD): -120dB (ADS127L01)
- 输出电流驱动能力: $\pm 4\text{mA}$
- 可通过编程设定的短路电流
- 经验证用于驱动 ADS88xx 系列逐次逼近寄存器 (SAR) ADC 和 ADS127xx 系列宽频带 Δ - Σ ADC 的 REF 引脚

2 应用

- 自动测试设备 (ATE) 测试器和示波器
- 测试和测量设备
- 可编程逻辑控制器 (PLC) 的模拟输入模块
- 医疗设备
- 精密数据采集系统

3 说明

REF6000 系列电压基准集成低输出阻抗缓冲器, 这使得用户能够直接驱动精密数据转换器的 REF 引脚, 同时维持线性度、失真和噪声性能。多数精密 SAR 和 Δ - Σ ADC 在转换过程中会将二进制加权电容切换到 REF 引脚。为了支持这一动态负载, 必须通过一个低输出阻抗 (高带宽) 缓冲器缓冲电压基准的输出。REF6000 系列器件非常适合 (但不限于) 驱动 ADS88xx 系列 SAR ADC 和 ADS127xx 系列 Δ - Σ ADC 以及其他数模转换器 (DAC) 的 REF 引脚。

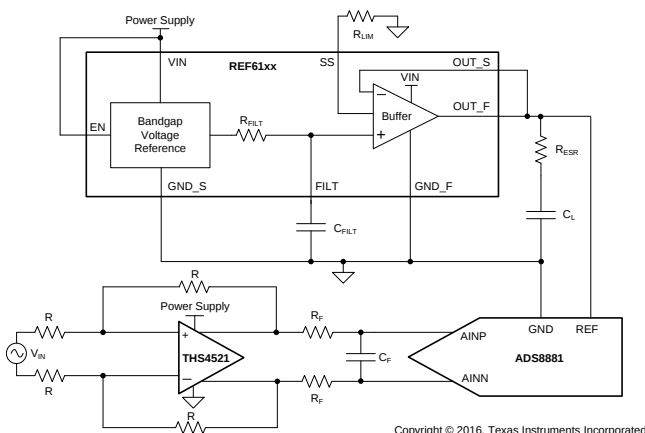
在驱动 ADS8881 的 REF 引脚时, 即使在首次转换过程中, REF6000 系列电压基准的输出电压也不会降至 1 LSB (18 位) 以下。该特性对于突发模式、事件触发的等时采样和可变采样率数据采集系统极为有用。REF6000 系列的 REF61xx 型号指定了最大温度漂移 (仅为 8ppm/°C), 可为电压基准与低输出阻抗缓冲器组合提供 0.05% 初始精度。关于 REF6000 系列中的多种温度漂移选项, 请参见 [器件比较表](#)。

器件信息⁽¹⁾

产品型号	封装	封装尺寸 (标称值)
REF61xx	VSSOP (8)	3.00mm x 3.00mm

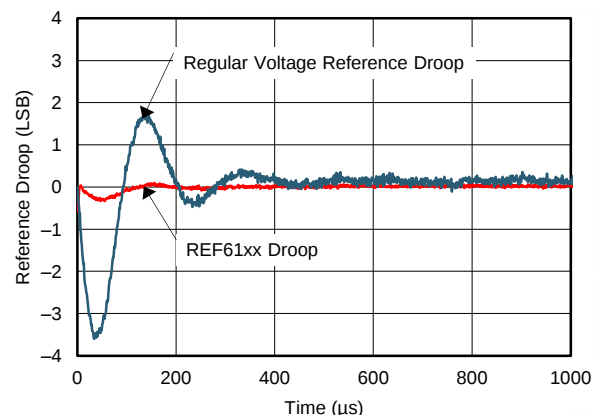
(1) 要了解所有可用封装, 请参见数据表末尾的封装选项附录。

典型应用



Copyright © 2016, Texas Instruments Incorporated

基准压降比较
(1 LSB = 19.07 μV , ADS8881 的速率为 1MSPS)



目录

1	特性	1	9.1	Overview	19
2	应用	1	9.2	Functional Block Diagram	19
3	说明	1	9.3	Feature Description	20
4	修订历史记录	2	9.4	Device Functional Modes	23
5	Device Comparison Table	3	10	Applications and Implementation	24
6	Pin Configuration and Functions	3	10.1	Application Information	24
7	Specifications	4	10.2	Typical Application	24
7.1	Absolute Maximum Ratings	4	11	Power Supply Recommendations	27
7.2	ESD Ratings	4	12	Layout	28
7.3	Recommended Operating Conditions	4	12.1	Layout Guidelines	28
7.4	Thermal Information	4	12.2	Layout Example	28
7.5	Electrical Characteristics	5	13	器件和文档支持	29
7.6	Typical Characteristics	7	13.1	文档支持	29
8	Parameter Measurement Information	14	13.2	相关链接	29
8.1	Solder Heat Shift	14	13.3	接收文档更新通知	29
8.2	Thermal Hysteresis	15	13.4	社区资源	29
8.3	Reference Droop Measurements	16	13.5	商标	29
8.4	1/f Noise Performance	18	13.6	静电放电警告	29
9	Detailed Description	19	13.7	Glossary	29
			14	机械、封装和可订购信息	30

4 修订历史记录

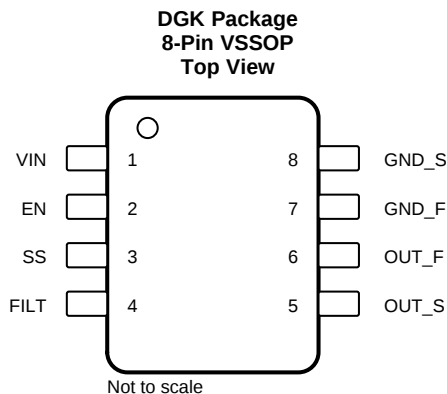
Changes from Revision A (June 2016) to Revision B	Page
• 已更改 说明	1
• Changed the <i>Device Comparison Table</i>	3
• Changed list of devices for output current in Recommended Operating Conditions	4
• Changed load regulation max value for REF6150 at $T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$ from 30 to 50	5
• Changed Figure 1	7
• Changed Figure 2	7
• Changed Figure 5	7
• Changed "second pass" to "final pass" in last paragraph of <i>Solder Heat Shift</i> section	14
• Added link to SLYY097 in <i>Overview</i> section	19

Changes from Original (May 2016) to Revision A	Page
• 已由“产品预览”更改为“量产数据”	1

5 Device Comparison Table

DEVICE FAMILY	TEMPERATURE DRIFT
REF60xx	5 ppm/°C from –40 to 125°C
REF61xx	8 ppm/°C from –40 to 125°C
REF62xx	3 ppm/°C from 0 to 70°C

6 Pin Configuration and Functions



Pin Functions

PIN		TYPE	DESCRIPTION
NAME	NO.		
EN	2	Input	Enable pin
FILT	4	—	Filter capacitor pin. A capacitor (C_{FILT}) $\geq 1 \mu F$ must be connected between the FILT pin and ground for stability.
GND_F	7	Ground	Ground force pin
GND_S	8	Ground	Ground sense pin
OUT_F	6	Output	Output voltage force pin
OUT_S	5	Input	Output voltage sense pin
SS	3	—	Short circuit current limit pin. Connect a resistor to this pin to set the output short-circuit current limit. Connect to VIN pin for highest current limit
VIN	1	Power	Input supply voltage pin

7 Specifications

7.1 Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
Input voltage	V_{IN}	–0.3	6	V
	V_{EN}	–0.3	$V_{IN} + 0.3$	V
Operating temperature, T_A		–55	150	°C
Junction temperature, T_J			150	°C
Storage temperature, T_{stg}		–65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

7.2 ESD Ratings

		VALUE	UNIT
$V_{(ESD)}$ Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±1000	V
	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±250	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

		MIN	NOM	MAX	UNIT
V_{IN} Supply input voltage ($I_{OUT} = 0$ mA)	REF6125	3		5.5	V
	REF6130, REF6133, REF6141, REF6145	$V_{OUT} + 0.25$		5.5	
	REF6150	5.3		5.5	
V_{EN} Enable voltage		0		V_{IN}	V
I_L Output current	REF6125, REF6130, REF6133, REF6141	–4		4	mA
	REF6145	–3.5		3.5	
	REF6150	–3		3	
T_A Operating temperature		–40	25	125	°C

7.4 Thermal Information

THERMAL METRIC ⁽¹⁾		REF61xx	UNIT
		DGK (VSSOP)	
		8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	158.5	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	51.2	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	79.5	°C/W
ψ_{JT}	Junction-to-top characterization parameter	5.2	°C/W
ψ_{JB}	Junction-to-board characterization parameter	78.0	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

7.5 Electrical Characteristics

at $T_A = 25^\circ\text{C}$, $V_{IN} = 5\text{ V}$ for all devices except REF6150, $V_{IN} = 5.4\text{ V}$ for REF6150, $I_L = 0\text{ mA}$, $C_L = 22\text{ }\mu\text{F}$, $C_{FILT} = 1\text{ }\mu\text{F}$, and $V_{EN} = 5\text{ V}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS			MIN	TYP	MAX	UNIT
ACCURACY AND DRIFT								
Output voltage accuracy					-0.05%	0.05%		
Output voltage temperature coefficient ⁽¹⁾						8		ppm/°C
LINE AND LOAD REGULATION								
$\Delta V_{O(\Delta V)}$ Line regulation	REF6125 REF6130, REF6133, REF6141, REF6145 REF6150	$V_{OUT} + 0.5\text{ V} \leq V_{IN} \leq 5.5\text{ V}$	$T_A = 25^\circ\text{C}$	4	20	ppm/V		
			$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$	30				
		$V_{OUT} + 0.25\text{ V} \leq V_{IN} \leq 5.5\text{ V}$	$T_A = 25^\circ\text{C}$	4	20			
			$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$	30				
		$V_{OUT} + 0.3\text{ V} \leq V_{IN} \leq 5.5\text{ V}$	$T_A = 25^\circ\text{C}$	7	60			
			$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$	120				
$\Delta V_{O(\Delta I)}$ Load regulation, sourcing and sinking	REF6125, REF6130, REF6133, REF6141 REF6145 REF6150	$I_L = 0\text{ mA}$ to 4 mA , $V_{IN} = V_{OUT} + 600\text{ mV}$	$T_A = 25^\circ\text{C}$	2	20	ppm/mA		
			$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$	30				
		$I_L = 0\text{ mA}$ to 3.5 mA , $V_{IN} = V_{OUT} + 600\text{ mV}$	$T_A = 25^\circ\text{C}$	2	20			
			$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$	30				
		$I_L = 0\text{ mA}$ to 3 mA , $V_{IN} = V_{OUT} + 400\text{ mV}$	$T_A = 25^\circ\text{C}$	2	20			
			$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$	50				
I_{SC} Short-circuit current	SS = open				10.5		mA	
NOISE								
Total integrated noise	$C_L = 22\text{ }\mu\text{F}$				5		μV_{RMS}	
	$C_L = 47\text{ }\mu\text{F}$				5			
Low frequency noise	$0.1\text{ Hz} \leq f \leq 10\text{ Hz}$				3		$\mu\text{V}_{PP}/\text{V}$	
OUTPUT IMPEDANCE								
Output impedance	$f = \text{DC}$ to 200 kHz , $C_L = 47\text{ }\mu\text{F}$				50		m Ω	
TURN-ON TIME								
t_{on} Turn-on time	0.1% settling, $C_L = 47\text{ }\mu\text{F}$, SS = open, REF6125				100		ms	
HYSTERESIS AND LONG TERM DRIFT								
Long term stability	0 to 1000h at 25°C				80		ppm	
	1000h to 2000h at 25°C				20			
Output voltage hysteresis ⁽²⁾	25°C , -40°C , 125°C , 25°C (cycle 1)				33		ppm	
	25°C , -40°C , 125°C , 25°C (cycle 2)				8			
CAPACITIVE LOAD								
C_L Stable output capacitor value					10	47	μF	

(1) Temperature drift is specified according to the box method. See the [Feature Description](#) section for more details.

(2) See the [Thermal Hysteresis](#) section.

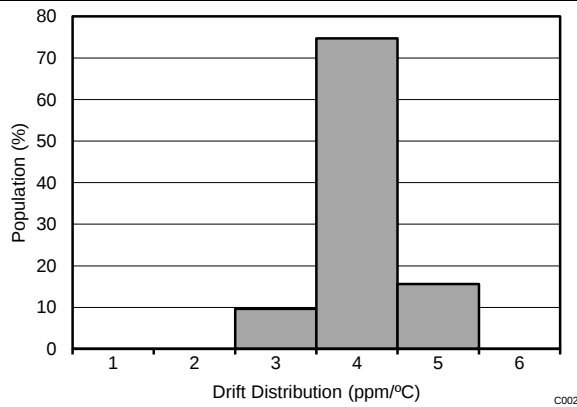
Electrical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $V_{IN} = 5\text{ V}$ for all devices except REF6150, $V_{IN} = 5.4\text{ V}$ for REF6150, $I_L = 0\text{ mA}$, $C_L = 22\text{ }\mu\text{F}$, $C_{FILT} = 1\text{ }\mu\text{F}$, and $V_{EN} = 5\text{ V}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS			MIN	TYP	MAX	UNIT
OUTPUT VOLTAGE								
V _{OUT}	Output voltage	REF6125			2.5		V	
		REF6130			3			
		REF6133			3.3			
		REF6141			4.096			
		REF6145			4.5			
		REF6150			5			
POWER SUPPLY								
I _{CC}	Supply current	REF6125, REF6130, REF6133, REF6141	Active mode, V _{EN} = 5 V	T _A = 25°C	0.82	0.90	mA	
				T _A = −40°C to +125°C		1.1		
		REF6145, REF6150	Active mode, V _{EN} = 5 V	T _A = 25°C	0.83	0.95		
				T _A = −40°C to +125°C		1.15		
		Shutdown mode, V _{EN} = 0 V		T _A = 25°C	1	3	μA	
				T _A = −40°C to +125°C		15		
Enable pin voltage		Voltage reference in active mode (EN = 1)			1.6		V	
		Voltage reference in shutdown mode (EN = 0)			0.6			
Enable pin current		V _{EN} = 5 V			100	150	nA	
Dropout voltage		REF6125		I _L = 0 mA	500	500	mV	
				I _L = 4 mA		600		
		REF6130, REF6133, REF6141		I _L = 0 mA	50	250		
				I _L = 4 mA		600		
		REF6145		I _L = 0 mA	50	250		
				I _L = 3.5 mA		600		
		REF6150		I _L = 0 mA	100	300		
				I _L = 3 mA		400		

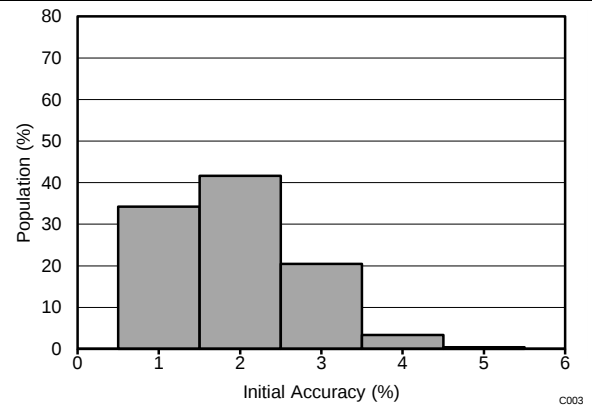
7.6 Typical Characteristics

at $T_A = 25^\circ\text{C}$, $I_L = 0\text{ mA}$, and $V_{IN} = 5\text{ V}$, using REF6125 (unless otherwise noted)



$T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$

Figure 1. Drift Distribution



$T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$

Figure 2. Initial Accuracy Distribution

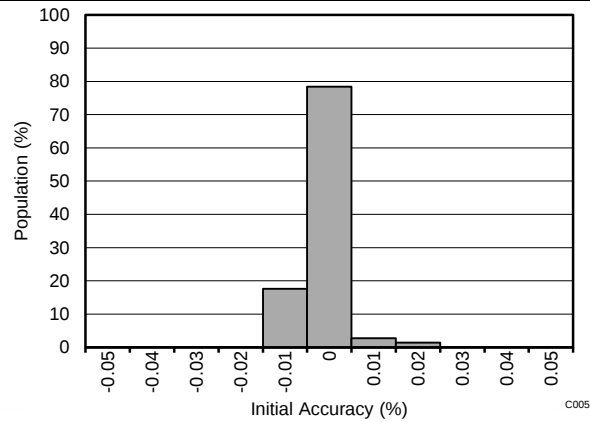


Figure 3. Initial Accuracy Distribution

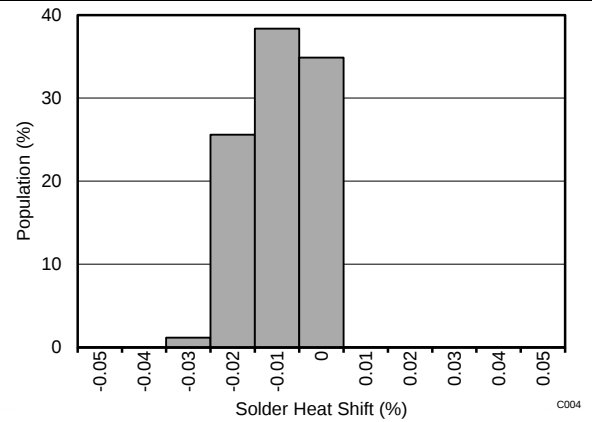


Figure 4. Solder-Heat Shift Distribution

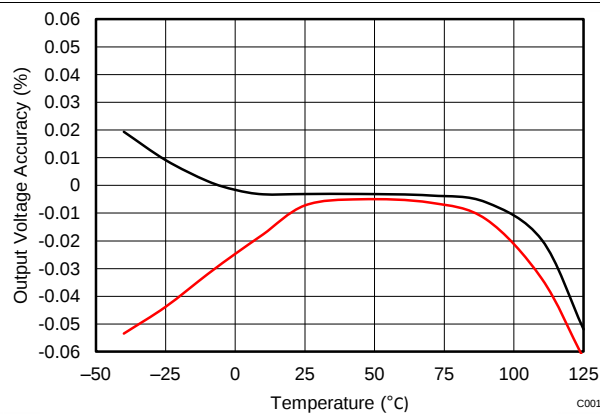


Figure 5. Output Voltage Accuracy vs Temperature

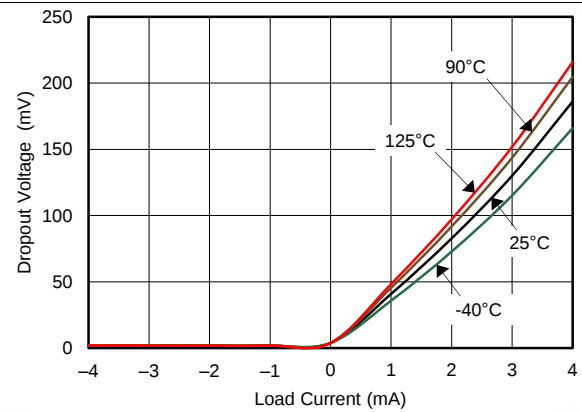
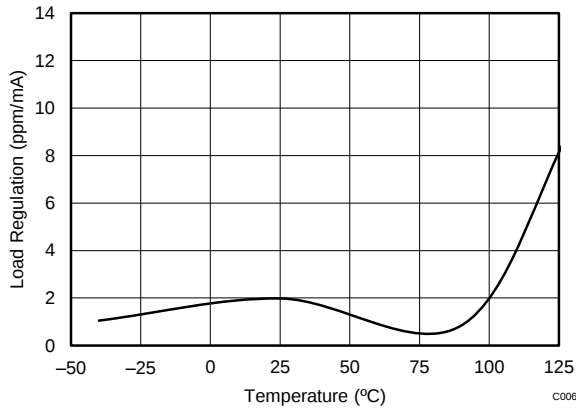


Figure 6. Dropout Voltage vs Load Current

Typical Characteristics (continued)

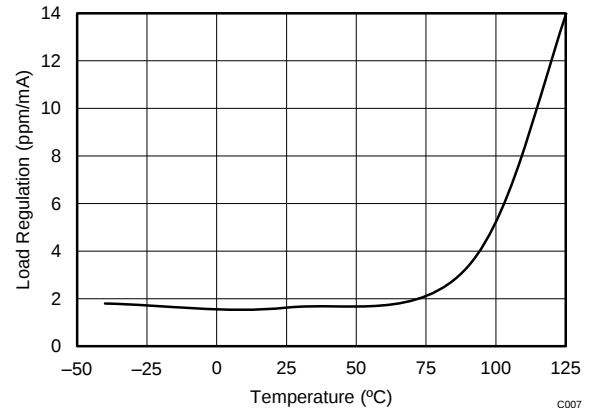
at $T_A = 25^\circ\text{C}$, $I_L = 0\text{ mA}$, and $V_{IN} = 5\text{ V}$, using REF6125 (unless otherwise noted)



$$V_{IN} = V_{OUT} + 600\text{ mV},$$

$$I_L = 0\text{ mA to }4\text{ mA}$$

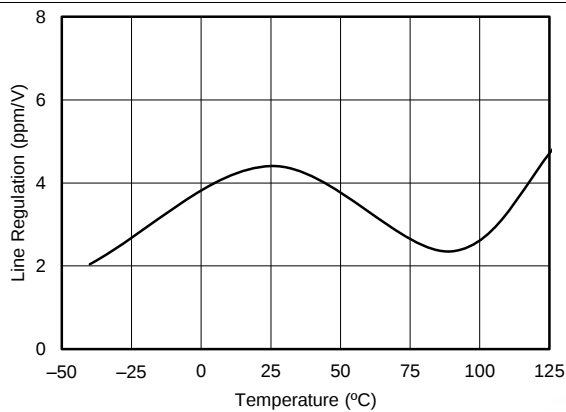
Figure 7. Load Regulation Sourcing vs Temperature



$$V_{IN} = V_{OUT} + 600\text{ mV},$$

$$I_L = 0\text{ mA to }4\text{ mA}$$

Figure 8. Load Regulation Sinking vs Temperature



$$V_{OUT} + 0.25\text{ V} \leq V_{IN} \leq 5.5\text{ V}$$

Figure 9. Line Regulation vs Temperature

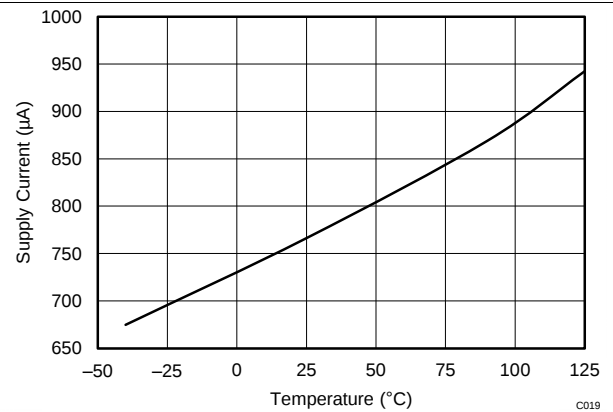


Figure 10. Supply Current vs Temperature

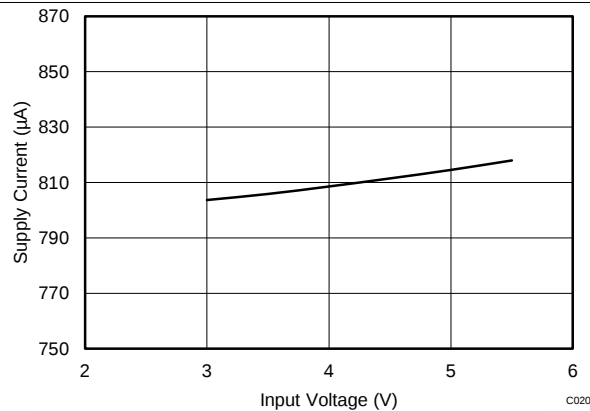


Figure 11. Supply Current vs Input Voltage

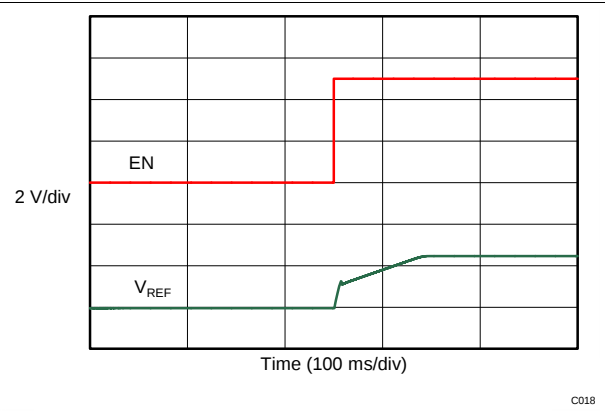
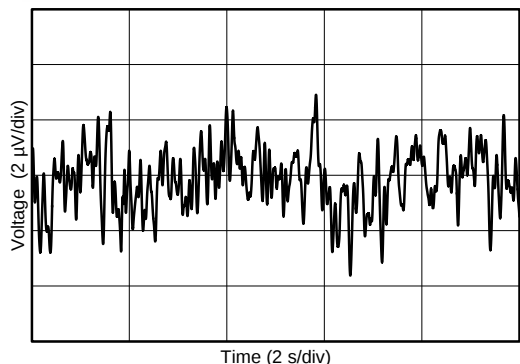


Figure 12. Turn-On Settling Time

Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $I_L = 0\text{ mA}$, and $V_{IN} = 5\text{ V}$, using REF6125 (unless otherwise noted)



C021

Figure 13. 0.1-Hz to 10-Hz Noise

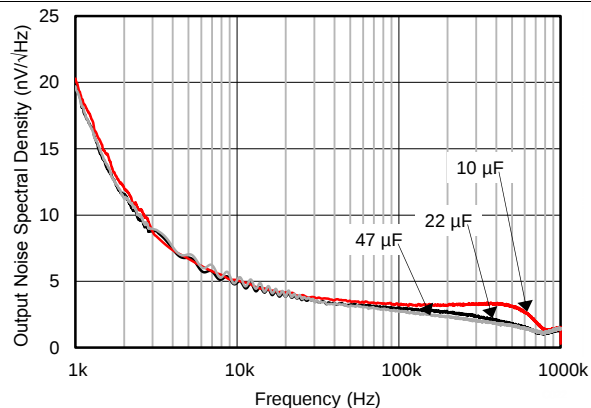


Figure 14. Output-Voltage Noise Spectrum

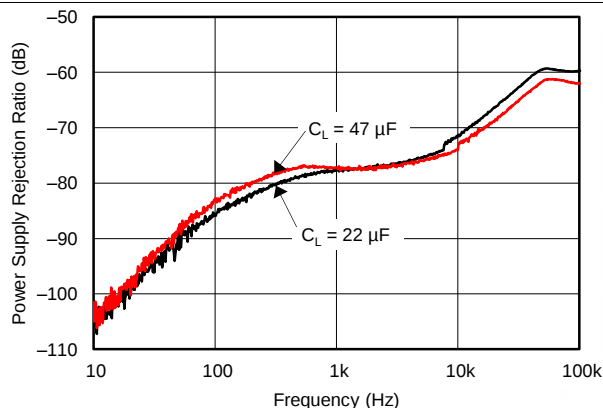
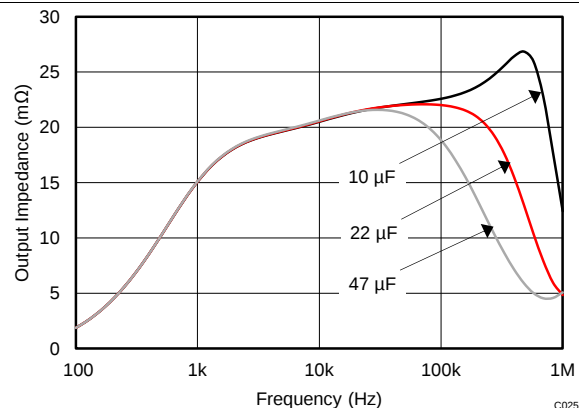


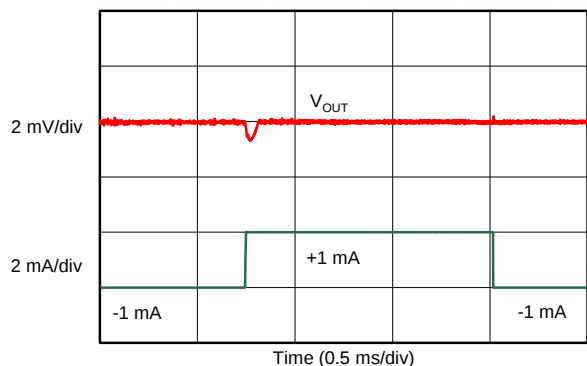
Figure 15. PSRR vs Frequency



C025

Graph obtained by design simulation

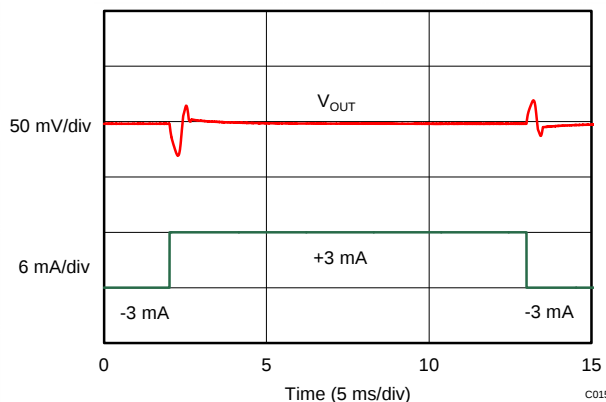
Figure 16. Output Impedance vs Frequency



C014

Load current = $\pm 1\text{ mA}$

Figure 17. Load Transient Response



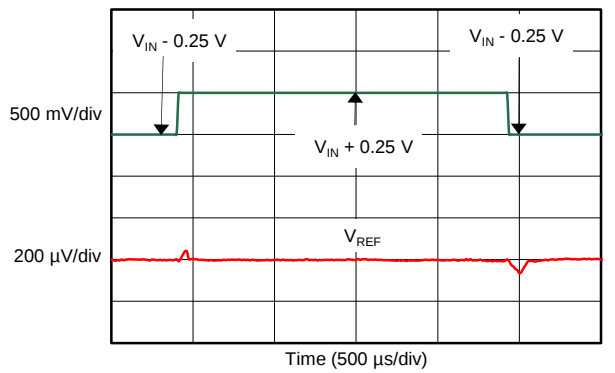
C015

Load current = $\pm 3\text{ mA}$

Figure 18. Load Transient Response

Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $I_L = 0\text{ mA}$, and $V_{IN} = 5\text{ V}$, using REF6125 (unless otherwise noted)



C013

Figure 19. Line Transient Response

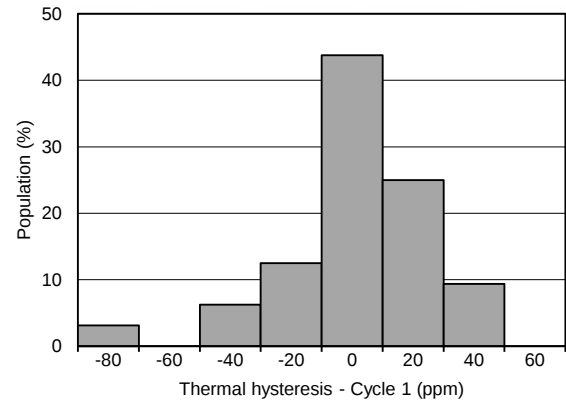


Figure 20. Thermal Hysteresis Distribution (Cycle 1)

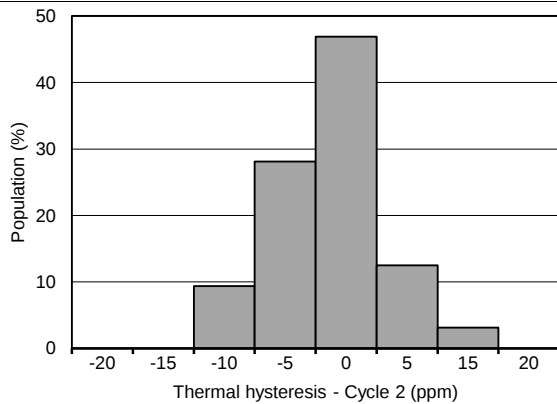


Figure 21. Thermal Hysteresis Distribution (Cycle 2)

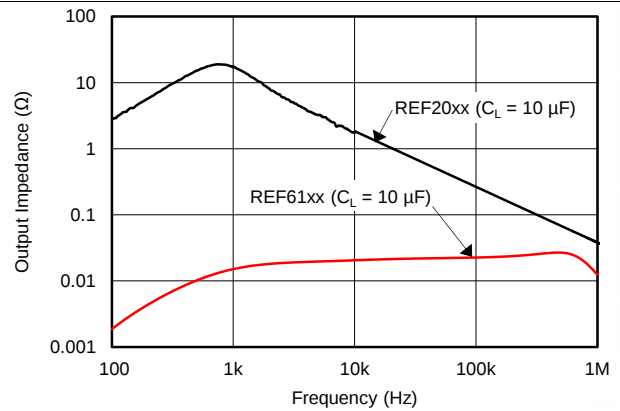
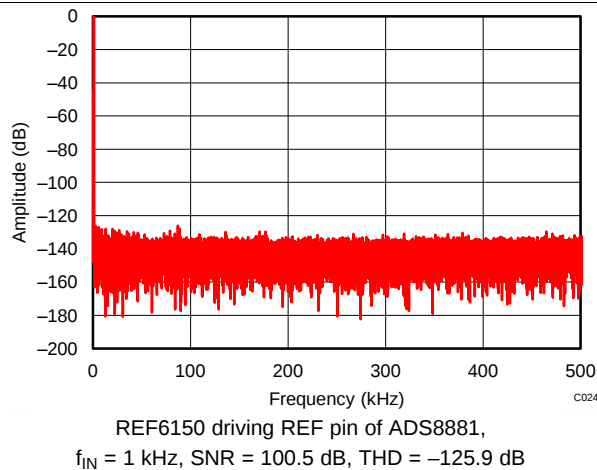


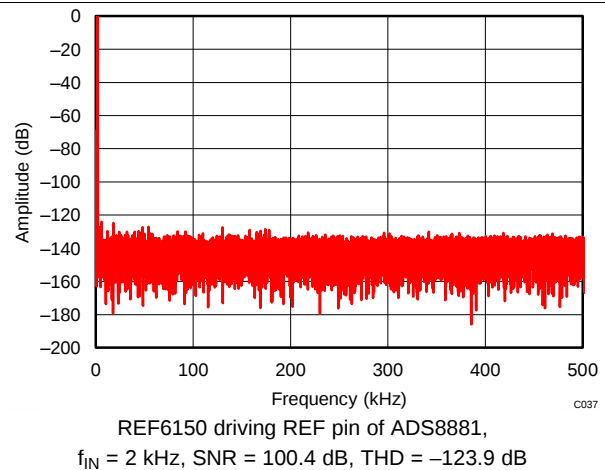
Figure 22. Output Impedance Comparison



C024

REF6150 driving REF pin of ADS8881,
 $f_{IN} = 1\text{ kHz}$, SNR = 100.5 dB, THD = -125.9 dB

Figure 23. Typical FFT Plot



C037

REF6150 driving REF pin of ADS8881,
 $f_{IN} = 2\text{ kHz}$, SNR = 100.4 dB, THD = -123.9 dB

Figure 24. Typical FFT Plot

Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $I_L = 0\text{ mA}$, and $V_{IN} = 5\text{ V}$, using REF6125 (unless otherwise noted)

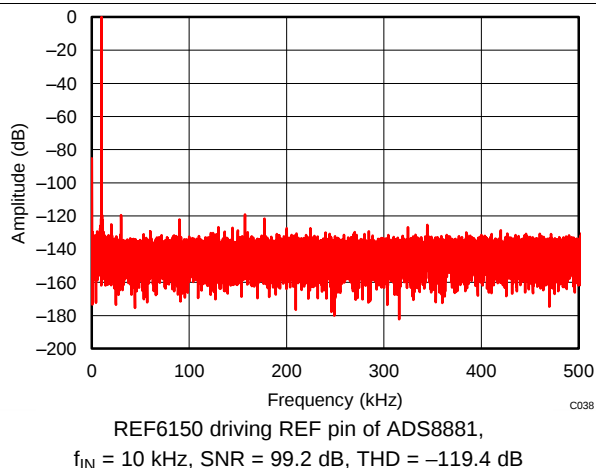


Figure 25. Typical FFT Plot

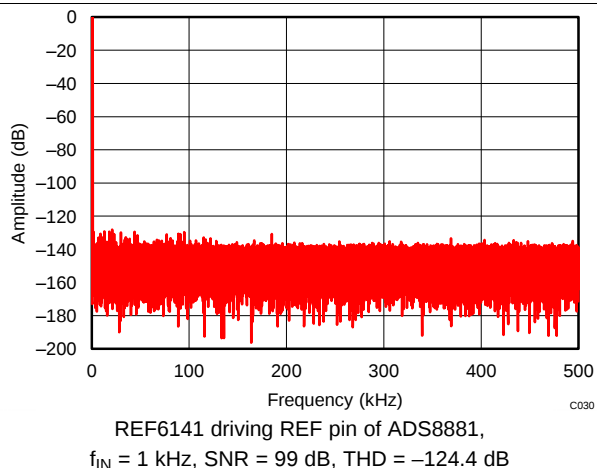


Figure 26. Typical FFT Plot

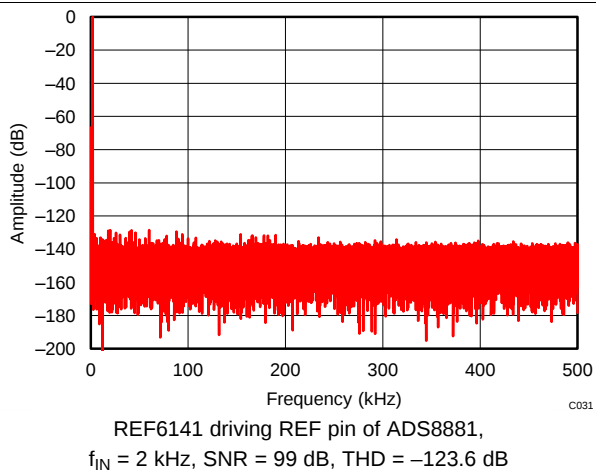


Figure 27. Typical FFT Plot

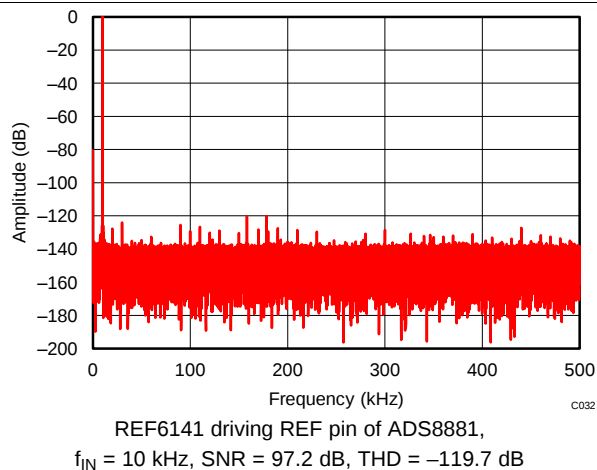


Figure 28. Typical FFT Plot

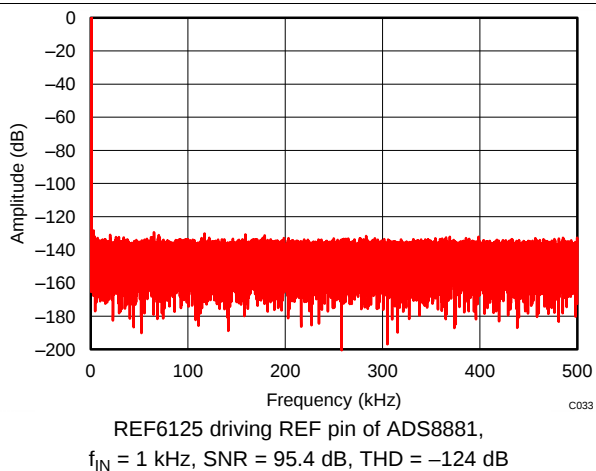


Figure 29. Typical FFT Plot

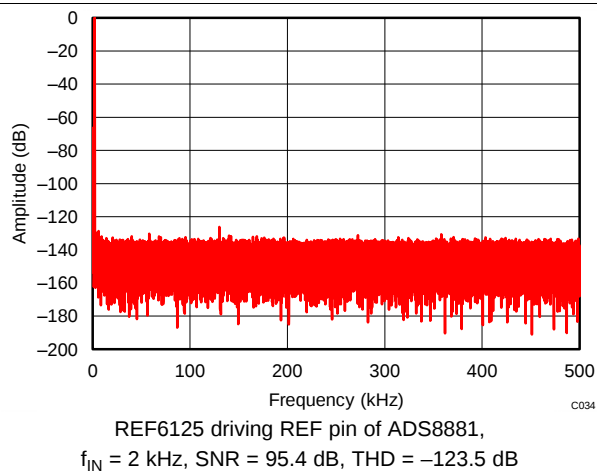


Figure 30. Typical FFT Plot

Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $I_L = 0\text{ mA}$, and $V_{IN} = 5\text{ V}$, using REF6125 (unless otherwise noted)

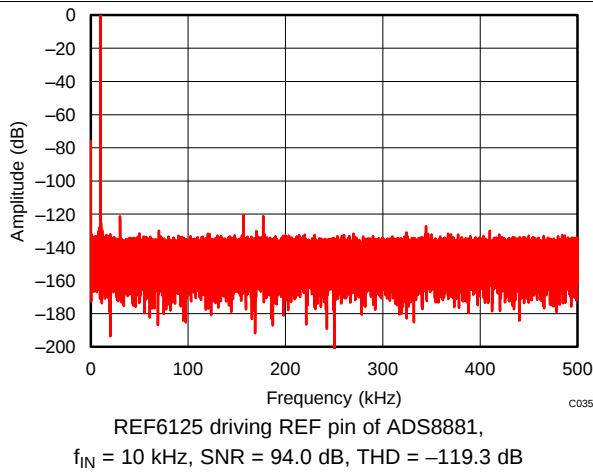


Figure 31. Typical FFT Plot

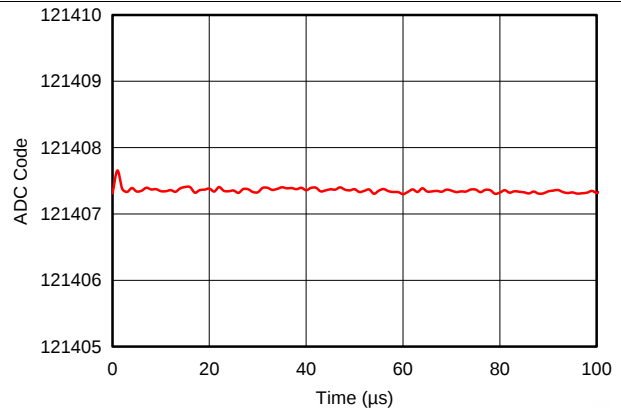


Figure 32. Reference Droop

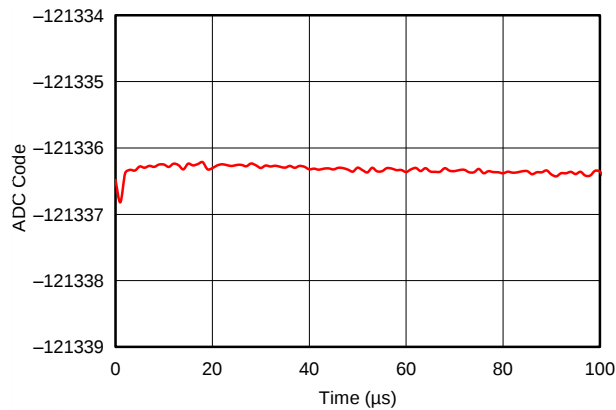


Figure 33. Reference Droop

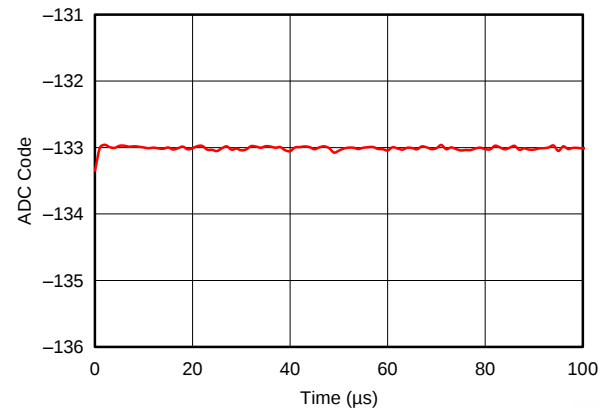


Figure 34. Reference Droop

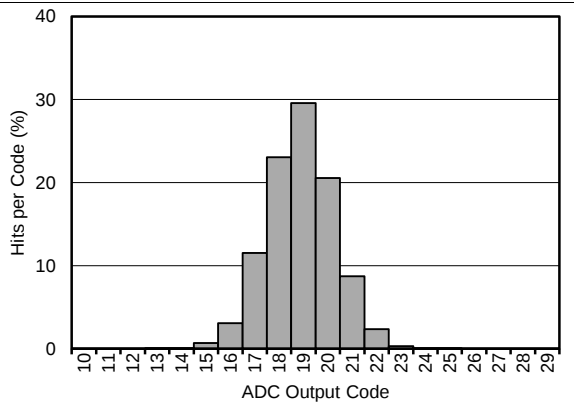


Figure 35. DC Input Histogram

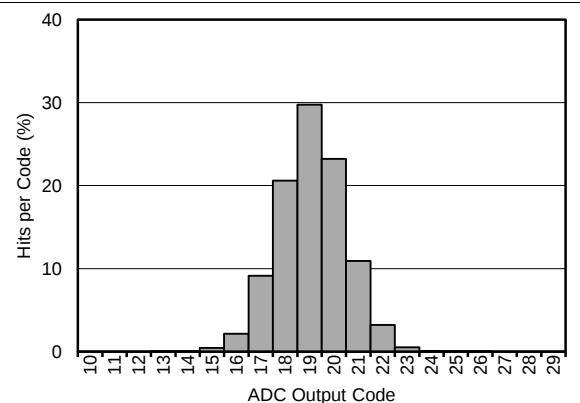
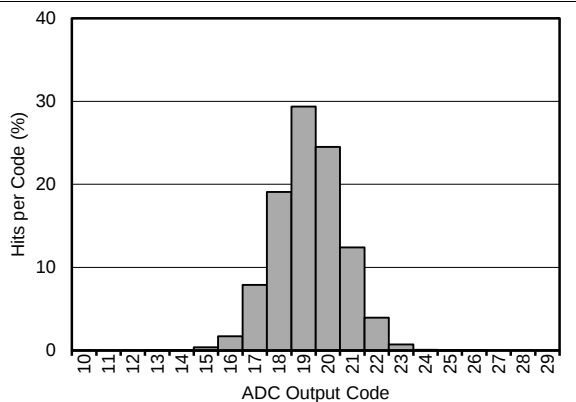


Figure 36. DC Input Histogram

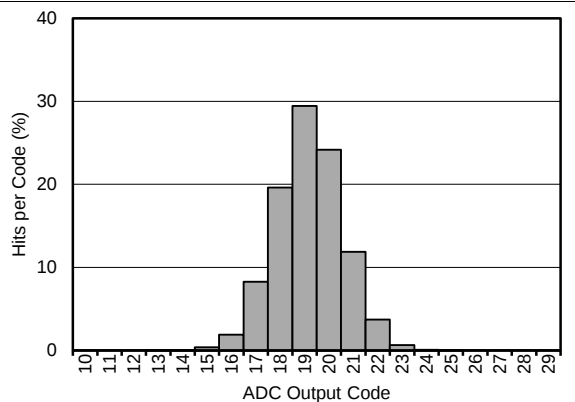
Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $I_L = 0\text{ mA}$, and $V_{IN} = 5\text{ V}$, using REF6125 (unless otherwise noted)



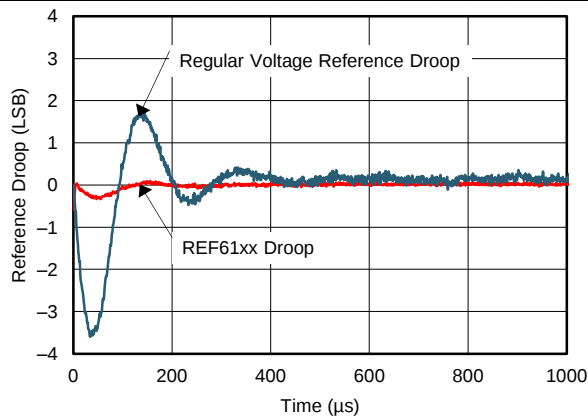
AINP = AINN = $V_{REF} / 2$ for ADS8881,
sampling rate = 100 kSPS

Figure 37. DC Input Histogram



AINP = AINN = $V_{REF} / 2$ for ADS8881,
sampling rate = 20 kSPS

Figure 38. DC Input Histogram



1 LSB = $19.07\text{ }\mu\text{V}$, with ADS8881 at 1 MSPS

Figure 39. Reference Droop Comparison

8 Parameter Measurement Information

8.1 Solder Heat Shift

The materials used in the manufacture of the REF61xx have differing coefficients of thermal expansion, and result in stress on the device die when the part is heated. Mechanical and thermal stress on the device die sometimes causes the output voltages to shift, degrading the initial accuracy specifications of the product. Reflow soldering is a common cause of this error.

In order to illustrate this effect, a total of 128 devices were soldered on eight printed circuit boards (PCBs), with 16 devices on each PCB, using lead-free solder paste, and the manufacturer-suggested reflow profile. The reflow profile is as shown in [Figure 40](#). The printed circuit board is comprised of FR4 material. The board thickness is 1.65 mm and the area is 101.6 mm × 127 mm.

The reference output voltage is measured before and after the reflow process; the typical shift is displayed in [Figure 41](#). Although all tested units exhibit very low shifts (< 0.03%), higher shifts are also possible depending on the size, thickness, and material of the PCB.

The histogram displays the typical shift for exposure to a single reflow profile. Exposure to multiple reflows, as is common on PCBs with surface-mount components on both sides, causes additional shifts in the output bias voltage. If the PCB is exposed to multiple reflows, solder the device in the final pass to minimize exposure to thermal stress.

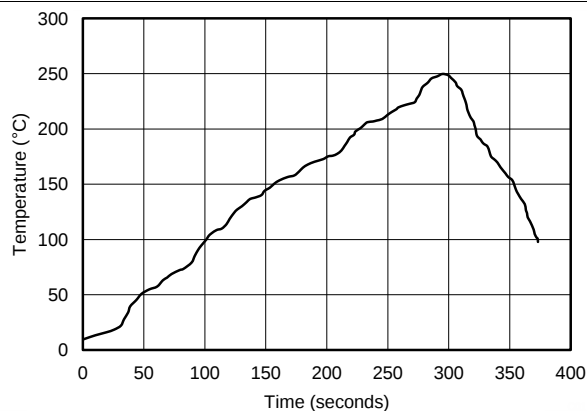


Figure 40. Reflow Profile

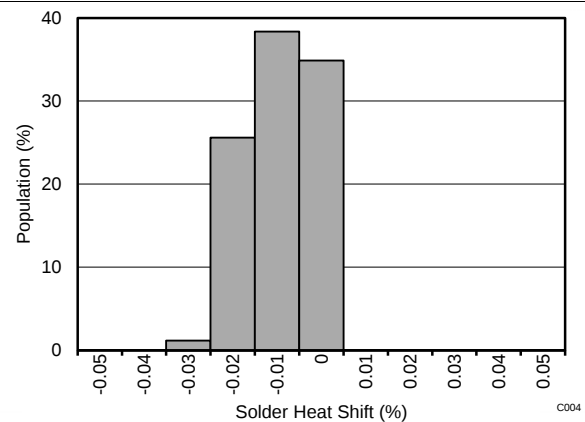


Figure 41. Solder Heat Shift Distribution

8.2 Thermal Hysteresis

Thermal hysteresis for the device is defined as the change in output voltage after operating the device at 25°C, cycling the device through the specified temperature range, and returning to 25°C. Thermal hysteresis was measured with the REF61xx soldered to a PCB, similar to a real-world application. The PCB was baked at 150°C for 30 minutes before thermal hysteresis was measured. Thermal hysteresis is expressed as:

$$V_{\text{HYST}} = \left(\frac{|V_{\text{PRE}} - V_{\text{POST}}|}{V_{\text{NOM}}} \right) \cdot 10^6 \text{ (ppm)}$$

where

- V_{HYST} = thermal hysteresis (in units of ppm).
- V_{NOM} = the specified output voltage.
- V_{PRE} = output voltage measured at 25°C pretemperature cycling.
- V_{POST} = output voltage measured after the device has cycled from 25°C through the specified temperature range of –40°C to 125°C and returns to 25°C.

(1)

Typical thermal hysteresis distribution is shown in [Figure 42](#) and [Figure 43](#).

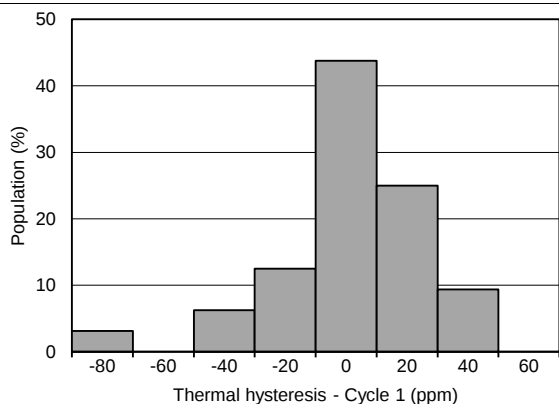


Figure 42. Thermal Hysteresis Distribution (Cycle 1)

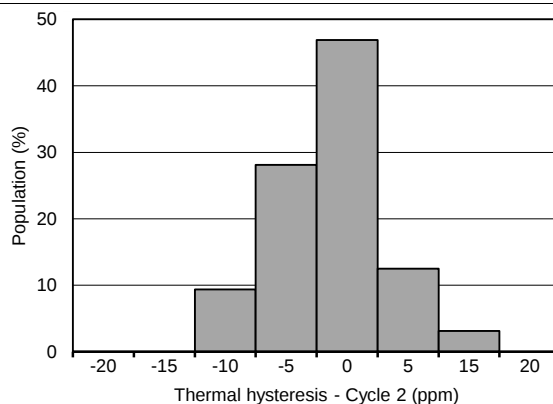
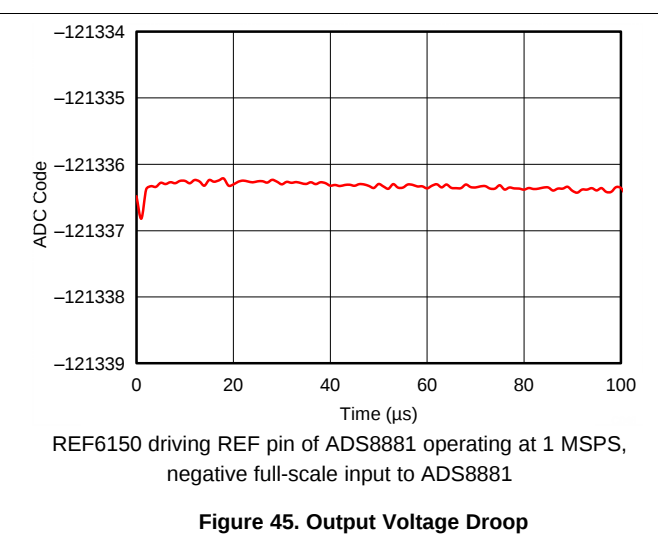
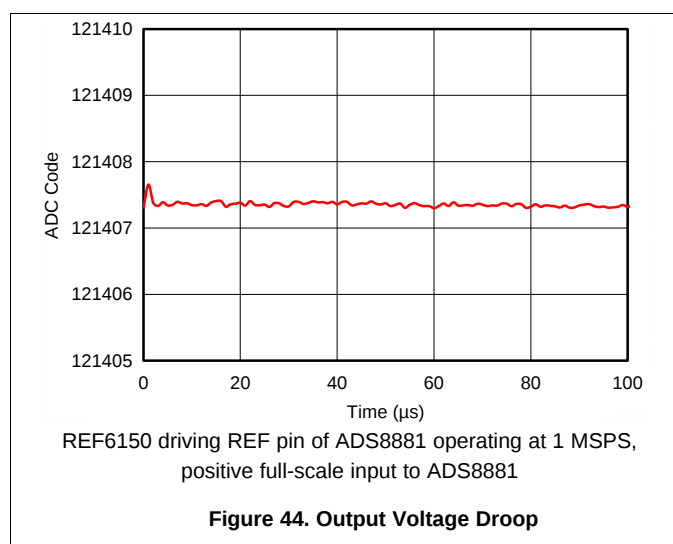


Figure 43. Thermal Hysteresis Distribution (Cycle 2)

8.3 Reference Droop Measurements

Many applications, such as event-triggered and multiplexed data-acquisition systems, require the very first conversion of the ADC to have 18-bit or greater precision. These types of data-acquisition systems capture data in bursts, and are also called burst-mode, data-acquisition systems. Achieving 18-bit precision for the first sample is a very difficult using a conventional voltage reference because the voltage reference droop limits the accuracy of the first few conversions. The REF61xx have an integrated ADC drive buffer that makes sure the reference droop is less than 1 LSB at 18-bit precision when used with the ADS8881, even at full throughput. [Figure 44](#) and [Figure 45](#) show the REF61xx output voltage droop when driving the REF pin of the ADS8881 at positive and negative full-scale inputs, respectively.



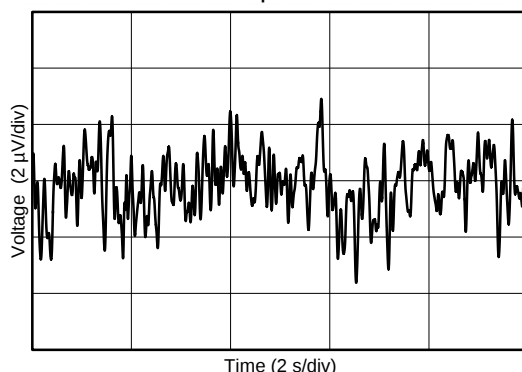
Direct measurement of the reference droop to 18-bit accuracy can be a challenging process. Therefore, the plots in [Figure 44](#) and [Figure 45](#) were obtained by processing the output code of the ADC. The ADC output code is given by:

$$C = (\text{Input Voltage} / V_{\text{REF}}) \times 2^N \quad (2)$$

If the input voltage is kept constant, V_{REF} is computed by monitoring the ADC output code C . The ADC code usually has six to seven LSBs of code spread due to the inherent noise of the ADC. In order to measure reference droop, this noise must be reduced drastically. Noise reduction is done by averaging the output code multiple times, as described in the next paragraph.

8.4 1/f Noise Performance

Typical 0.1-Hz to 10-Hz voltage noise for the REF6125 is shown in Figure 47. The 1/f noise scales with output voltage, but remains $3\ \mu\text{V}_{\text{PP}}/\text{V}$ for all the variants. Peak-to-peak noise measurement setup is shown in Figure 48.



C021

Figure 47. 0.1-Hz to 10-Hz Noise

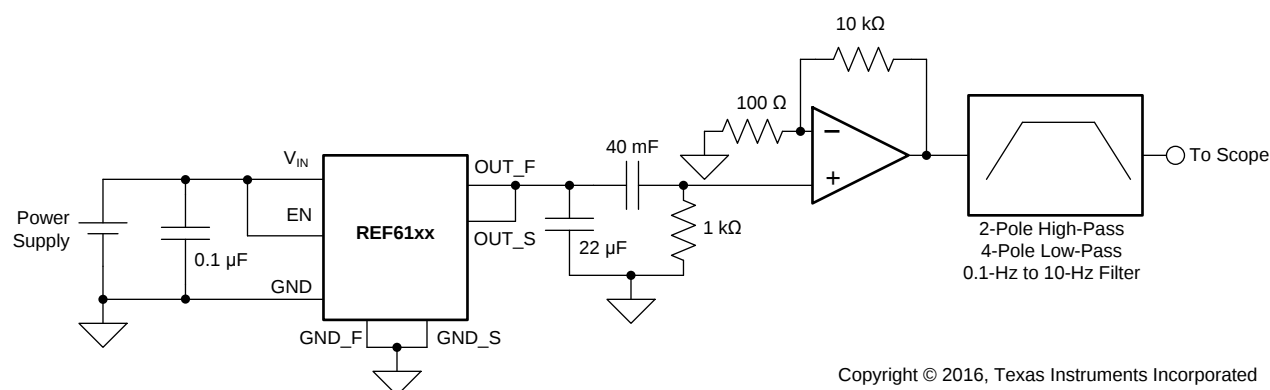


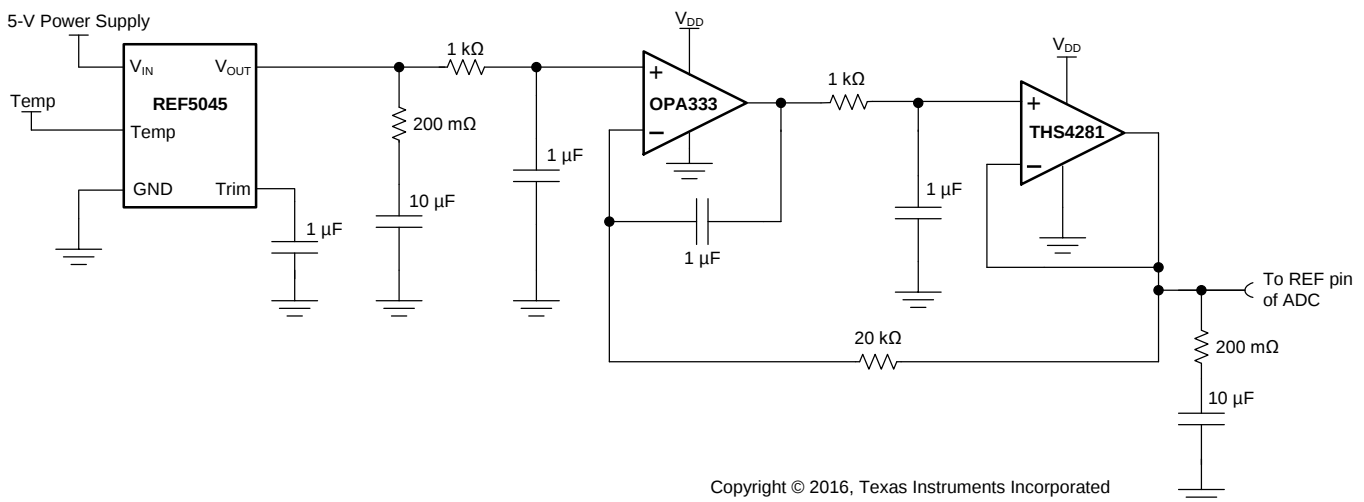
Figure 48. 0.1-Hz to 10-Hz Noise Measurement Setup

9.3 Feature Description

9.3.1 Integrated ADC Drive Buffer

Many ADC data sheets specify a few microamps of average current draw from the REF pin. Almost all voltage references provide these few microamps of average current; but not all voltage references are practical for driving a high-resolution, high-throughput SAR ADC because the peak current drawn can be very high when the capacitors are switched on the REF pin. The worst-case demand for the voltage reference is during a burst-mode conversion, when the ADC is idle for a very long time, before a conversion is initiated, and the first sample converted is expected to be precise. Usually, a large capacitor is connected between the REF pin and ground pin (or sometimes between the REFP and REFM pins) of the ADC to smoothen the current load and reduce the burden on the voltage reference. The voltage reference must then be capable of providing the average current required to completely charge the reference capacitor, but without causing the reference voltage to droop significantly. Most voltage references lack the ability to completely charge the reference capacitor, and settle when the binary-weighted capacitors are being switched onto the REF pin because of the large output impedance. Usually, voltage references have output impedances in the range of 10's of ohms at frequencies higher than 100 Hz. The output voltage of the voltage reference must be buffered with a low output impedance (usually high bandwidth) amplifier to achieve excellent linearity and distortion performance.

The key amplifier specifications to be considered when designing a reference buffer for a high-precision ADC are: low offset, low drift, wide bandwidth, and low output impedance. While it is possible to select an amplifier that sufficiently meets all these requirements, the amplifier comes at a cost of excessive power consumption. For example, the [OPA350](#) is a 38-MHz bandwidth amplifier with a maximum offset of 0.5 mV, and low offset drift of 4 $\mu\text{V}/^\circ\text{C}$, but consumes a quiescent current of 5.2mA. This is because (from an amplifier design perspective) offset and drift are dc specifications, whereas bandwidth, low output impedance, and high capacitive drive capability are high-frequency specifications. Therefore, achieving all the performance in one amplifier requires power. However, a more efficient design to meet the low power budget is to use a composite reference buffer, which uses an amplifier with superior high-frequency specifications in the feedback loop of a dc precision amplifier to get the overall performance at much lower power consumption. [Figure 49](#) shows such a composite amplifier design with the [OPA333](#) (dc precision amplifier) and [THS4281](#) (high-bandwidth amplifier). This reference buffer design requires three devices, and a large number of external components. This solution still consumes close to 2 mA of quiescent current.



Copyright © 2016, Texas Instruments Incorporated

Figure 49. Composite Amplifier Reference Buffer

Feature Description (continued)

9.3.2 Temperature Drift

The REF61xx family is designed for minimal drift error, defined as the change in output voltage over temperature. The drift is calculated using the box method, as described by the following equation:

$$\text{Drift} = \left(\frac{V_{\text{REF(MAX)}} - V_{\text{REF(MIN)}}}{V_{\text{REF}} \cdot \text{Temperature Range}} \right) \cdot 10^6 \quad (\text{ppm}) \quad (3)$$

9.3.3 Load Current

The REF6125, REF6130, REF6133 and REF6141 are specified to deliver current load of ± 4 mA. The REF6145 is specified to deliver ± 3.5 mA, and the REF6150 is specified to deliver ± 3 mA. The REF61xx are protected from short circuits at the output by limiting the output short-circuit current.

The short-circuit current limit (I_{SC}) of the REF61xx family of devices is adjusted by connecting a resistor (R_{SS}) on the SS pin. The short-circuit current limit when the REF61xx device is sourcing current can be calculated as shown in [Equation 4](#):

$$I_{\text{SC}} = (80 \cdot 10^{-9}) \cdot R_{\text{SS}} + (3 \cdot 10^{-3}) \quad (4)$$

The short circuit current limit when the REF61xx device is sinking is calculated as shown in [Equation 5](#):

$$I_{\text{SC}} = (115 \cdot 10^{-9}) \cdot R_{\text{SS}} + (4.6 \cdot 10^{-3}) \quad (5)$$

The recommended output current of the REF61xx also depends on the resistor connected to the SS pin. The recommended output current (sourcing and sinking) for the REF6125, REF6130, REF6133 and REF6141 is given by [Equation 6](#):

$$I_{\text{L}} = (31.25 \cdot 10^{-9}) \cdot R_{\text{SS}} + (0.25 \cdot 10^{-3}) \quad (6)$$

The recommended output current (sourcing and sinking) for the REF6145 is given by [Equation 7](#):

$$I_{\text{L}} = (27.08 \cdot 10^{-9}) \cdot R_{\text{SS}} + (0.25 \cdot 10^{-3}) \quad (7)$$

The recommended output current (sourcing and sinking) for the REF6150 is given by [Equation 8](#):

$$I_{\text{L}} = (23.75 \cdot 10^{-9}) \cdot R_{\text{SS}} + (0.15 \cdot 10^{-3}) \quad (8)$$

The temperature of the device increases according to [Equation 9](#):

$$T_{\text{J}} = T_{\text{A}} + P_{\text{D}} \cdot R_{\theta\text{JA}}$$

where:

- T_{J} = junction temperature ($^{\circ}\text{C}$).
 - T_{A} = ambient temperature ($^{\circ}\text{C}$).
 - P_{D} = power dissipated (W).
 - $R_{\theta\text{JA}}$ = junction-to-ambient thermal resistance ($^{\circ}\text{C}/\text{W}$).
- (9)

The REF61xx maximum junction temperature must not exceed the absolute maximum rating of 150°C .

Feature Description (continued)

9.3.4 Stability

The REF61xx family of voltage references are stable with output capacitor values ranging from 10 μF to 47 μF . At a low output-capacitor value of 10 μF , an effective series resistance (ESR) of 20 m Ω to 100 m Ω is required for stability; whereas, at a higher value of 47 μF , an ESR of 5 m Ω to 100 m Ω is required. The shaded region in [Figure 53](#) shows the stable region of operation for the REF61xx devices.

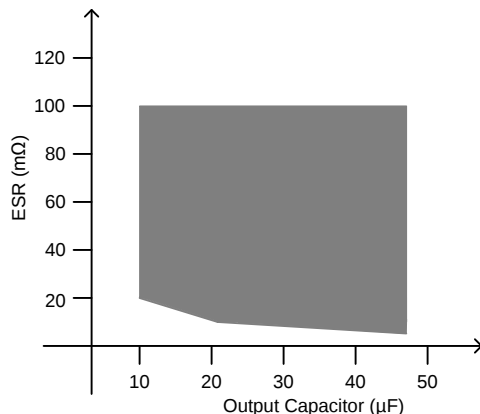


Figure 53. Stable Output Capacitor Range

A capacitor of value 1 μF is required at the FILT pin for stability and noise performance. A low ESR (5 m Ω to 20 m Ω) is easily achieved by increasing the PCB trace length, thus eliminating the need for a discrete resistor. Higher values of ESR (greater than 20 m Ω , but lesser than 100 m Ω) can be intentionally added to increase the output bandwidth of the REF61xx. This higher ESR improves the transient performance of the REF61xx, but worsens noise performance because of increased bandwidth.

9.4 Device Functional Modes

When the EN pin of the REF61xx is pulled high, the device is in active mode. The device must be in active mode for normal operation.

To place the REF61xx into a shutdown mode, pull the ENABLE pin low. When in shutdown mode, the output of the device becomes high impedance and the quiescent current of the device reduces to 1 μA (typ). See the enable pin voltage parameter in the [Electrical Characteristics](#) table for logic high and logic low voltage levels.

10 Applications and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

10.1 Application Information

Many applications, such as event-triggered and multiplexed data-acquisition systems, require the very first conversion of the ADC to have 18-bit or greater precision. These types of data acquisition systems capture data in bursts, and are also called burst-mode, data-acquisition systems. Achieving 18-bit precision for the first sample is very difficult using a conventional voltage reference because the voltage reference droop limits the accuracy of the first few conversions. Furthermore, variable-sampling-rate systems require that the gain error of the system does not vary with sampling rate. The primary objective of this design example is to demonstrate the lowest distortion and noise, burst-mode data-acquisition block with low power consumption, using an 18-bit SAR ADC operating at a throughput of 1 MSPS, for a 1-kHz, full-scale, pure sine-wave input.

10.2 Typical Application

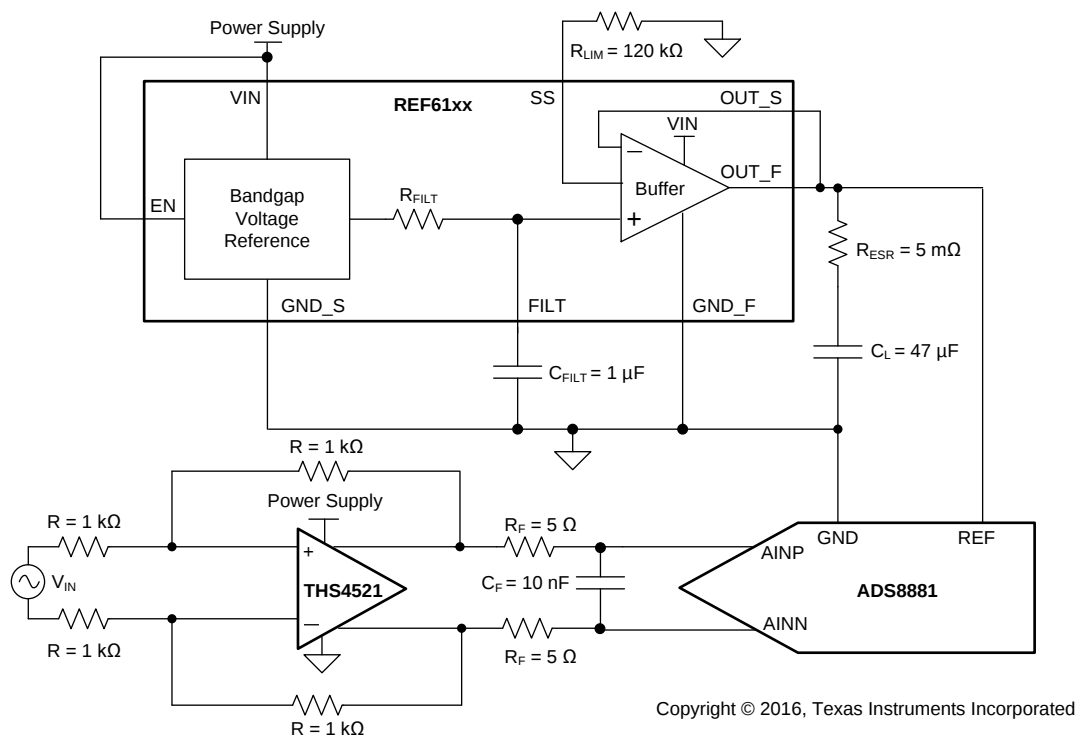


Figure 54. 18-bit, 1-MSPS, Burst-Mode Data Acquisition system

10.2.1 Design Requirements

1. Burst-mode support (see [Reference Droop Measurements](#) section for more details)
2. ENOB > 16 bits
3. THD < -120 dB
4. Power consumption < 50 mW
5. Throughput = 1 MSPS

Typical Application (continued)

10.2.2 Detailed Design Procedure

The data acquisition system shown in [Figure 54](#) has three major contributors to the noise and accuracy in the system: the input driver, the reference with driver, and the data converter. Each analog block is carefully designed so that the data converter specifications limit the system specifications. The [THS4551](#), a fully differential operational amplifier is used to drive the 18-bit ADC ([ADS8881](#)). The charge-kickback RC filter at the output of the THS4551 is used to reduce the charge kickback created by the opening and closing of the sampling switch inside the ADC. Design the RC filter so that the voltage at the sampling capacitor settles to 18-bit accuracy within the acquisition time of the ADC.

Data-acquisition systems require stable and accurate voltage references in order to perform the most accurate data conversion. The REF61xx family of voltage references have integrated an ADC drive buffer, and can therefore drive the REF pin of the ADS8881 directly, without the need for an external reference buffer. See the [Integrated ADC Drive Buffer](#) section for more details about reference-buffer requirements. Correct output capacitor selection for the REF61xx is very important in this design. The [Stability](#) section describes the ESR requirements of the output capacitor for stability and burst-mode requirements. A capacitance of 1 μ F is connected to the FILT pin to reduce broadband noise of the REF61xx.

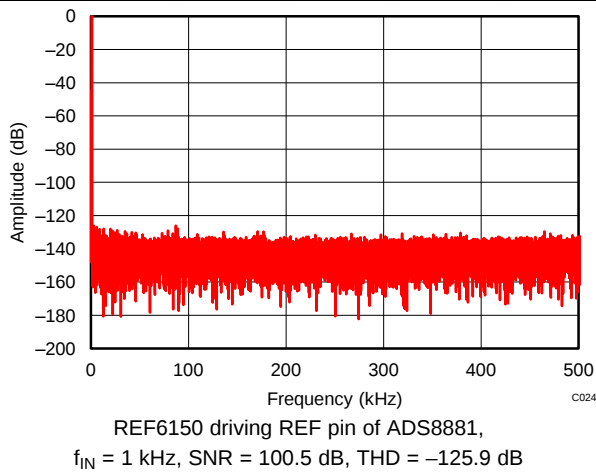
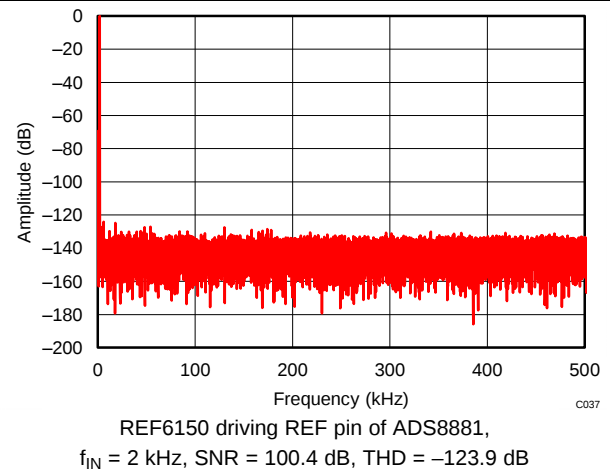
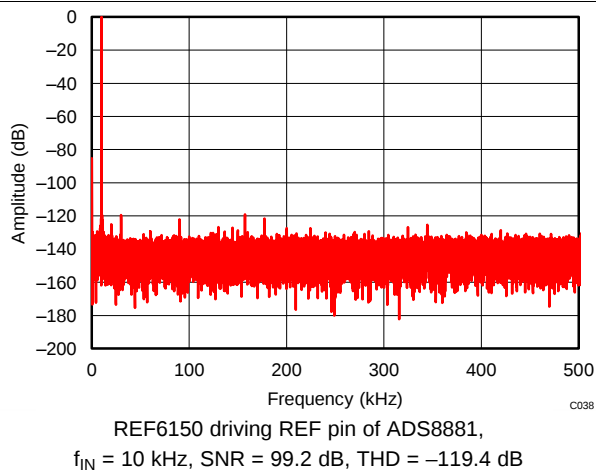
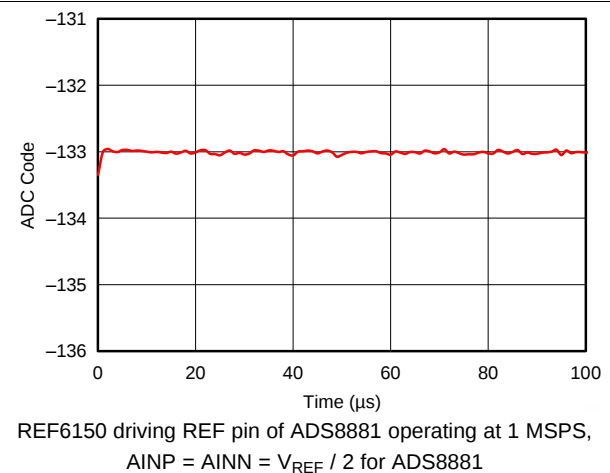
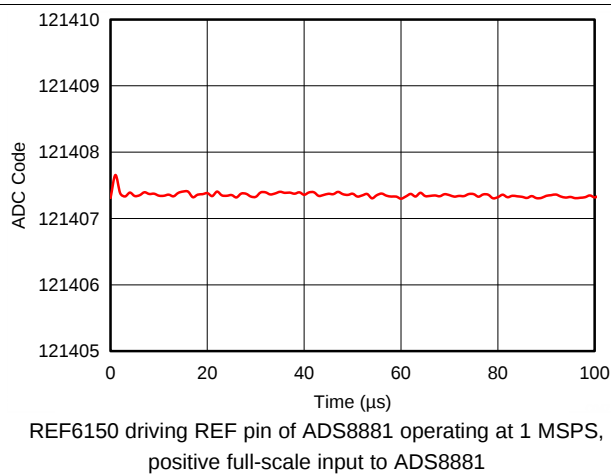
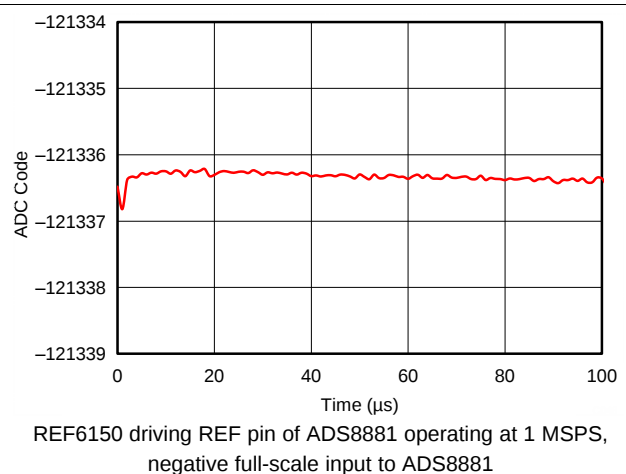
10.2.2.1 Results

[Table 1](#) summarizes the measured results.

Table 1. Measured Results

SPECIFICATION	MEASURED RESULT
SNR	100.5 dB
ENOB	16.4
THD	–125.9 dB
Throughput	1 MSPS
Burst mode	First sample > 18-bit precision
Power consumption	40 mW

10.2.3 Application Curves


Figure 55. Typical FFT Plot

Figure 56. Typical FFT Plot

Figure 57. Typical FFT Plot

Figure 58. Reference Droop

Figure 59. Reference Droop

Figure 60. Reference Droop

11 Power Supply Recommendations

The REF61xx family of references have extremely low dropout voltage. The dropout specifications can be found in the [Electrical Characteristics](#) section. A minimum 0.1 μF decoupling capacitor must be connected between the VIN and GND_F pins of the REF61xx. A typical dropout voltage versus load is shown in [Figure 61](#).

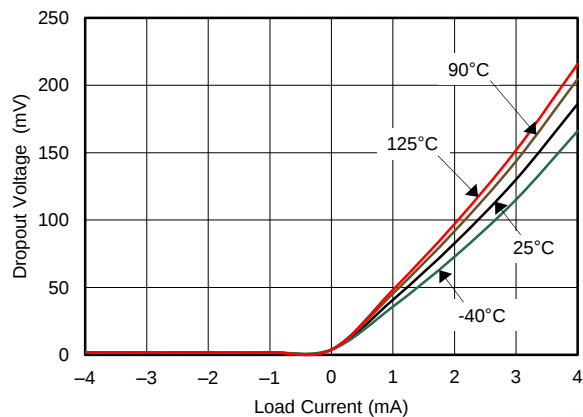


Figure 61. Dropout Voltage vs Load Current

12 Layout

12.1 Layout Guidelines

Figure 62 illustrates an example of a PCB layout for a data-acquisition system using the REF61xx. Some key considerations are:

- Connect low-ESR, 0.1- μ F ceramic bypass capacitors between the VIN pin and ground.
- Place the REF61xx output capacitor (C_L) and the ADC as close to each other as possible.
- Run two separate traces between VOUT_F, VOUT_S and the output capacitor, as shown in Figure 62.
- Short the GND_F and GND_S pins with a solid plane, and extend this plane to connect to the output capacitor C_L , as shown in Figure 62.
- Use a solid ground plane to help distribute heat and reduces electromagnetic interference (EMI) noise pickup.
- Place the external components as close to the device as possible. This configuration prevents parasitic errors (such as the Seebeck effect) from occurring.
- Do not run sensitive analog traces in parallel with digital traces. Avoid crossing digital and analog traces if possible, and only make perpendicular crossings when absolutely necessary.

12.2 Layout Example

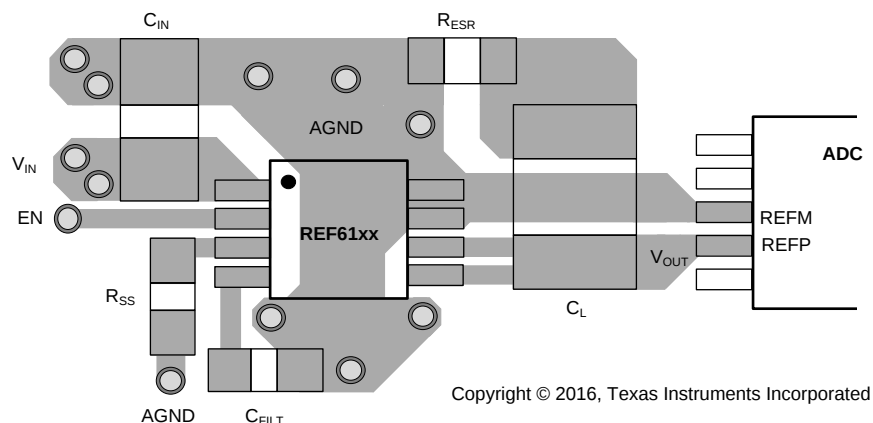


Figure 62. Layout Example

13 器件和文档支持

13.1 文档支持

13.1.1 相关文档

相关文档如下：

- [《ADS8881x 18 位、1MSPS、串行接口、低功耗、微型、真正的差分输入、SAR 模数转换器数据表》](#)（文献编号：SBAS547）
- [《ADS127L01 24 位、高速、高带宽模数转换器数据表》](#)（文献编号：SBAS607）
- [《REF6025EVM-PDK 用户指南》](#)（文献编号：SBAU258）
- [《电压基准对总谐波失真的影响》](#)（文献编号：SLYY097）

13.2 相关链接

下面的表格中列出了快速访问链接。范围包括技术文档、支持与社区资源、工具和软件，并且可以快速访问样片或购买链接。

表 2. 相关链接

器件	产品文件夹	样片与购买	技术文档	工具与软件	支持与社区
REF6125	请单击此处	请单击此处	请单击此处	请单击此处	请单击此处
REF6130	请单击此处	请单击此处	请单击此处	请单击此处	请单击此处
REF6133	请单击此处	请单击此处	请单击此处	请单击此处	请单击此处
REF6141	请单击此处	请单击此处	请单击此处	请单击此处	请单击此处
REF6145	请单击此处	请单击此处	请单击此处	请单击此处	请单击此处
REF6150	请单击此处	请单击此处	请单击此处	请单击此处	请单击此处

13.3 接收文档更新通知

如需接收文档更新通知，请访问 www.ti.com.cn 网站上的器件产品文件夹。点击右上角的提醒我 (Alert me) 注册后，即可每周定期收到已更改的产品信息。有关更改的详细信息，请查阅已修订文档中包含的修订历史记录。

13.4 社区资源

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

13.5 商标

E2E is a trademark of Texas Instruments.
All other trademarks are the property of their respective owners.

13.6 静电放电警告



ESD 可能会损坏该集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理措施和安装程序，可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级，大至整个器件故障。精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

13.7 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

14 机械、封装和可订购信息

以下页中包括机械、封装和可订购信息。这些信息是针对指定器件可提供的最新数据。这些数据会在无通知且不对本文档进行修订的情况下发生改变。欲获得该数据表的浏览器版本，请查阅左侧的导航栏。

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
REF6125IDGKR	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	14AV
REF6125IDGKR.B	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	14AV
REF6125IDGKT	Active	Production	VSSOP (DGK) 8	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	14AV
REF6125IDGKT.B	Active	Production	VSSOP (DGK) 8	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	14AV
REF6125IDGKTG4	Active	Production	VSSOP (DGK) 8	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	14AV
REF6125IDGKTG4.B	Active	Production	VSSOP (DGK) 8	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	14AV
REF6130IDGKR	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	14BV
REF6130IDGKR.B	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	14BV
REF6130IDGKT	Active	Production	VSSOP (DGK) 8	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	14BV
REF6130IDGKT.B	Active	Production	VSSOP (DGK) 8	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	14BV
REF6133IDGKR	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	14CV
REF6133IDGKR.B	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	14CV
REF6133IDGKT	Active	Production	VSSOP (DGK) 8	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	14CV
REF6133IDGKT.B	Active	Production	VSSOP (DGK) 8	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	14CV
REF6141IDGKR	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	14DV
REF6141IDGKR.B	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	14DV
REF6141IDGKT	Active	Production	VSSOP (DGK) 8	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	14DV
REF6141IDGKT.B	Active	Production	VSSOP (DGK) 8	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	14DV
REF6145IDGKR	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	14EV
REF6145IDGKR.B	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	14EV
REF6145IDGKT	Active	Production	VSSOP (DGK) 8	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	14EV
REF6145IDGKT.B	Active	Production	VSSOP (DGK) 8	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	14EV
REF6150IDGKR	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	14FV
REF6150IDGKR.B	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	14FV
REF6150IDGKT	Active	Production	VSSOP (DGK) 8	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	14FV
REF6150IDGKT.B	Active	Production	VSSOP (DGK) 8	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	14FV

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
REF6125IDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
REF6125IDGKT	VSSOP	DGK	8	250	177.8	12.4	5.3	3.4	1.4	8.0	12.0	Q1
REF6125IDGKTG4	VSSOP	DGK	8	250	177.8	12.4	5.3	3.4	1.4	8.0	12.0	Q1
REF6130IDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
REF6130IDGKT	VSSOP	DGK	8	250	177.8	12.4	5.3	3.4	1.4	8.0	12.0	Q1
REF6133IDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
REF6133IDGKT	VSSOP	DGK	8	250	177.8	12.4	5.3	3.4	1.4	8.0	12.0	Q1
REF6141IDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
REF6141IDGKT	VSSOP	DGK	8	250	177.8	12.4	5.3	3.4	1.4	8.0	12.0	Q1
REF6145IDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
REF6145IDGKT	VSSOP	DGK	8	250	177.8	12.4	5.3	3.4	1.4	8.0	12.0	Q1
REF6150IDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
REF6150IDGKT	VSSOP	DGK	8	250	177.8	12.4	5.3	3.4	1.4	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS

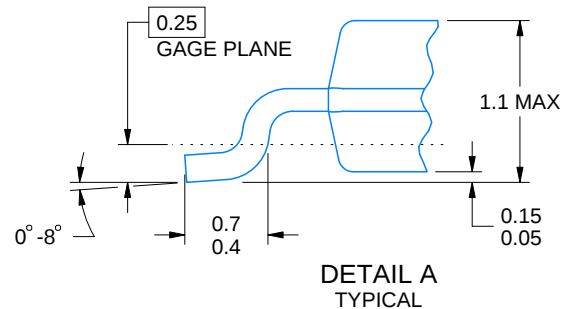
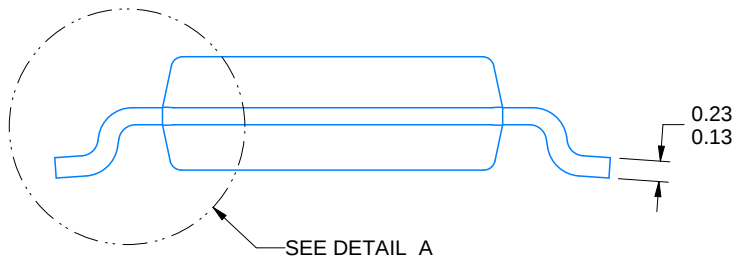


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
REF6125IDGKR	VSSOP	DGK	8	2500	346.0	346.0	29.0
REF6125IDGKT	VSSOP	DGK	8	250	223.0	270.0	35.0
REF6125IDGKTG4	VSSOP	DGK	8	250	223.0	270.0	35.0
REF6130IDGKR	VSSOP	DGK	8	2500	346.0	346.0	29.0
REF6130IDGKT	VSSOP	DGK	8	250	223.0	270.0	35.0
REF6133IDGKR	VSSOP	DGK	8	2500	346.0	346.0	29.0
REF6133IDGKT	VSSOP	DGK	8	250	223.0	270.0	35.0
REF6141IDGKR	VSSOP	DGK	8	2500	346.0	346.0	29.0
REF6141IDGKT	VSSOP	DGK	8	250	223.0	270.0	35.0
REF6145IDGKR	VSSOP	DGK	8	2500	346.0	346.0	29.0
REF6145IDGKT	VSSOP	DGK	8	250	223.0	270.0	35.0
REF6150IDGKR	VSSOP	DGK	8	2500	346.0	346.0	29.0
REF6150IDGKT	VSSOP	DGK	8	250	223.0	270.0	35.0



VSSOP - 1.1 mm max height

[illegible]

PowerPAD is a trademark of Texas Instruments.

- 
- TEXAS
INSTRUMENTS
www.ti.com

EXAMPLE BOARD LAYOUT

DGK0008A

TM VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



SOLDER MASK DETAILS

4214862/A 04/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.

EXAMPLE STENCIL DESIGN

DGK0008A

TM VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
SCALE: 15X

4214862/A 04/2023

NOTES: (continued)

11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.

重要通知和免责声明

TI“按原样”提供技术和可靠性数据（包括数据表）、设计资源（包括参考设计）、应用或其他设计建议、网络工具、安全信息和其他资源，不保证没有瑕疵且不做任何明示或暗示的担保，包括但不限于对适销性、某特定用途方面的适用性或不侵犯任何第三方知识产权的暗示担保。

这些资源可供使用 TI 产品进行设计的熟练开发人员使用。您将自行承担以下全部责任：(1) 针对您的应用选择合适的 TI 产品，(2) 设计、验证并测试您的应用，(3) 确保您的应用满足相应标准以及任何其他功能安全、信息安全、监管或其他要求。

这些资源如有变更，恕不另行通知。TI 授权您仅可将这些资源用于研发本资源所述的 TI 产品的相关应用。严禁以其他方式对这些资源进行复制或展示。您无权使用任何其他 TI 知识产权或任何第三方知识产权。您应全额赔偿因在这些资源的使用中对 TI 及其代表造成的任何索赔、损害、成本、损失和债务，TI 对此概不负责。

TI 提供的产品受 [TI 的销售条款](#) 或 [ti.com](#) 上其他适用条款/TI 产品随附的其他适用条款的约束。TI 提供这些资源并不会扩展或以其他方式更改 TI 针对 TI 产品发布的适用的担保或担保免责声明。

TI 反对并拒绝您可能提出的任何其他或不同的条款。

邮寄地址：Texas Instruments, Post Office Box 655303, Dallas, Texas 75265
版权所有 © 2025，德州仪器 (TI) 公司